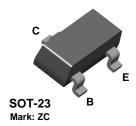


2N4124

MMBT4124





NPN General Purpose Amplifier

This device is designed as a general purpose amplifier and switch. The useful dynamic range extends to 100 mA as a switch and to 100 MHz as an amplifier.

Absolute Maximum Ratings*

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	25	V
V _{CBO}	Collector-Base Voltage	30	V
V _{EBO}	Emitter-Base Voltage	5.0	V
I _C	Collector Current - Continuous	200	mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics

TA = 25°C unless otherwise noted

Symbol	Characteristic	N	Units		
		2N4124	*MMBT4124		
P_D	Total Device Dissipation	625	350	mW	
	Derate above 25°C	5.0	2.8	mW/°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3		°C/W	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	357	°C/W	

^{*}Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

¹⁾ These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

NPN General Purpose Amplifier (continued)

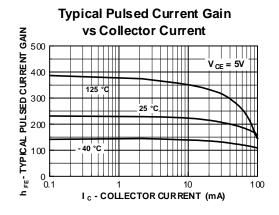
Electrical Characteristics			-											-				_	
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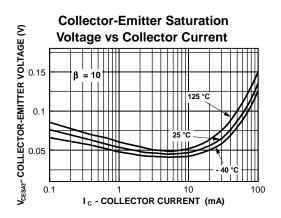
Symbol	Parameter	Test Conditions	Min	Max	Units
	•				
OFF CHA	RACTERISTICS				
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	$I_C = 1.0 \text{ mA}, I_B = 0$	25		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_C = 10 \mu A, I_E = 0$	30		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_{C} = 10 \mu A, I_{C} = 0$	5.0		V
I _{CBO}	Collector Cutoff Current	$V_{CB} = 20 \text{ V}, I_{E} = 0$		50	nA
I _{EBO}	Emitter Cutoff Current	$V_{EB} = 3.0 \text{ V}, I_{C} = 0$		50	nA
	Collector Emitter Ceturation Value	$I_C = 50 \text{ mA}, V_{CE} = 1.0 \text{ V}$	60	0.2	V
ON CHAR	ACTERISTICS*				
h _{FE}	DC Current Gain		120 60	360	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_C = 50 \text{ mA}, I_B = 5.0 \text{ mA}$		0.3	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	$I_C = 50 \text{ mA}, I_B = 5.0 \text{ mA}$		0.95	V
SMALL SI	GNAL CHARACTERISTICS				
f⊤	Current Gain - Bandwidth Product	$I_C = 10 \text{ mA}, V_{CE} = 20 \text{ V},$ f = 100 MHz	300		MHz
Output Capacitance					
	Output Capacitance	$V_{CB} = 5.0 \text{ V}, I_{E} = 0,$ f = 100 kHz		4.0	pF
	Output Capacitance Input Capacitance	7 2 7		4.0 8.0	
C _{ibo}		f = 100 kHz $V_{BE} = 0.5 \text{ V}, I_{C} = 0,$			pF
C _{ibo}	Input Capacitance	$\begin{split} f &= 100 \text{ kHz} \\ V_{BE} &= 0.5 \text{ V}, \text{ I}_{C} = 0, \\ f &= 1.0 \text{ kHz} \\ V_{CB} &= 5.0 \text{ V}, \text{ I}_{E} = 0, \end{split}$	120	8.0	pF pF

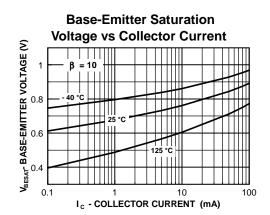
^{*}Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%

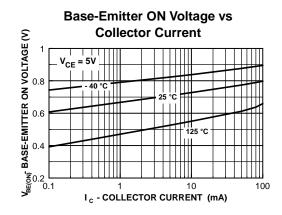
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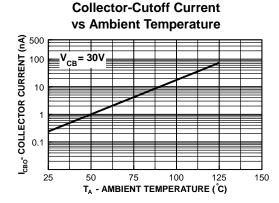
Typical Characteristics

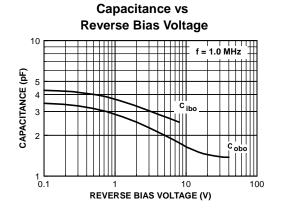






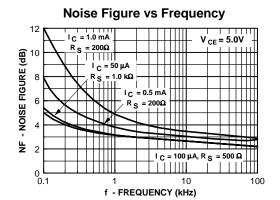


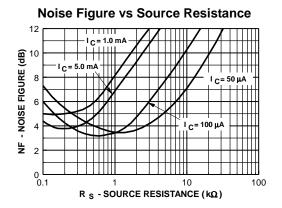


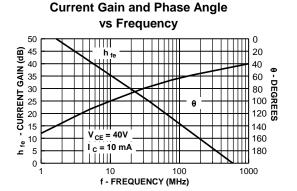


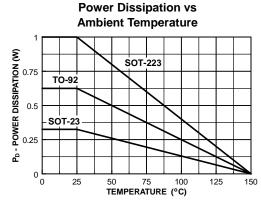
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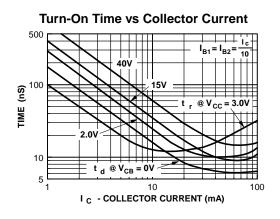
Typical Characteristics (continued)

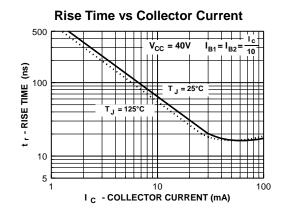








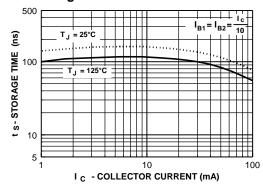




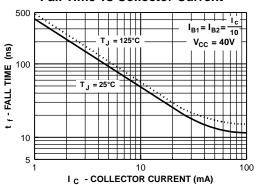
(continued)

Typical Characteristics (continued)

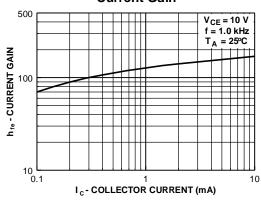
Storage Time vs Collector Current



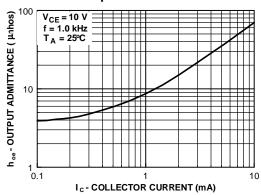
Fall Time vs Collector Current



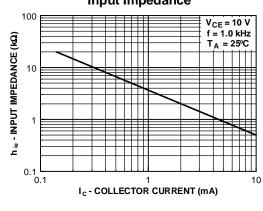
Current Gain



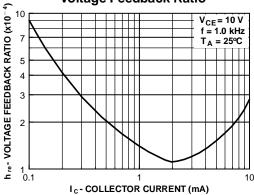
Output Admittance



Input Impedance



Voltage Feedback Ratio



(continued)

Test Circuits

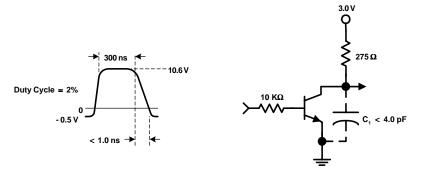


FIGURE 1: Delay and Rise Time Equivalent Test Circuit

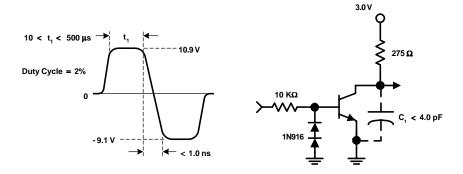


FIGURE 2: Storage and Fall Time Equivalent Test Circuit

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FPAB30BH60B FQP2N80 1.5KE16AG MT9V115EBKSTCH-GEVB NB6L295MNGEVB NB7L1008MNGEVB NC7WZ126K8X
NCL30000LED2GEVB NCN9252MUGEVB NCP1075PSRGEVB NCV4274CDT33RKG NCV887100D1R2G NDT2955 1N5339B
NSIC2030JBT3G NV890231MWTXGEVB CAT4101AEVB KA7818ETU S3JB 2SC5569-TD-E FEBFL7734_L55L008A 1V5KE39CA
FNB33060T AMIS30422DBGEVB AMIS3062XGEVK